# DSC5A01

## Silicon NPN epitaxial planar type

For low frequency amplification DSC2A01 in SMini3 type package

#### Features

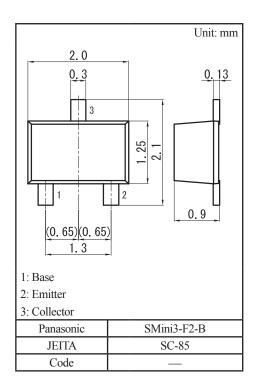
- $\bullet$  High forward current transfer ratio  $h_{FE}$  with excellent linearity
- Low collector-emitter saturation voltage  $V_{CE(sat)}$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)
- Marking Symbol: C8

#### Packaging

DSC5A01×0L Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	50	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	V <sub>CEO</sub> 40		
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	15	V	
Collector current	I <sub>C</sub>	50	mA	
Peak collector current	I <sub>CP</sub>	100	mA	
Collector power dissipation	P <sub>C</sub>	150	mW	
Junction temperature	Tj	150	°C	
Operating ambient temperature	T <sub>opr</sub>	-40 to +85	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	





#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu A, I_{\rm E} = 0$	50			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	40			V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	15			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = 20 \text{ V}, I_{B} = 0$			1	μΑ
Forward current transfer ratio *1	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$	400		2000	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1 \text{ mA}$		0.05	0.20	V
Transition frequency	$\mathbf{f}_{\mathrm{T}}$	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$		150		MHz

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*1: Rank classification

Code	R	S	Т	
Rank	R	S	Т	
$h_{\rm FE}$	400 to 800	600 to 1200	1000 to 2000	
Marking Symbol	C8R	C8S	C8T	

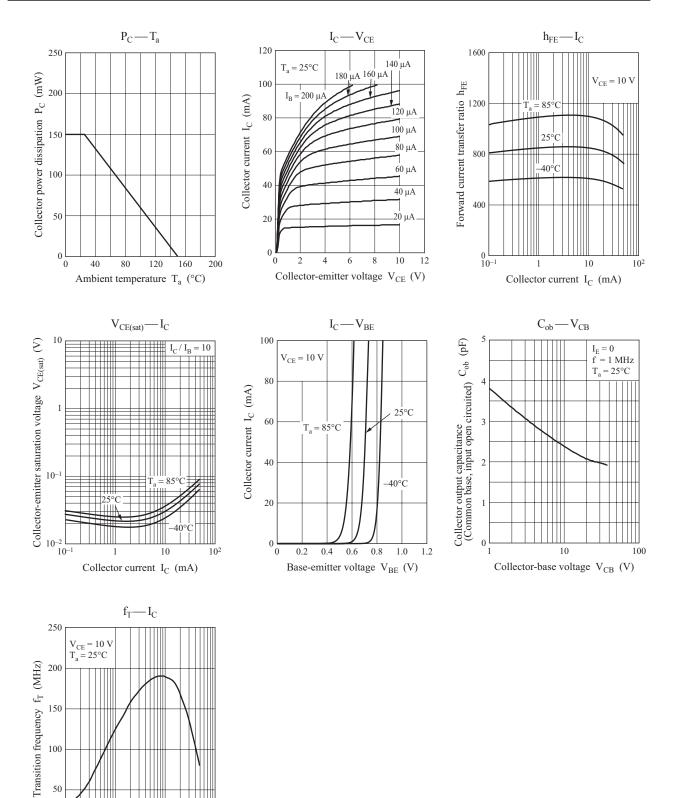
50

0 ∟ 0.1

10

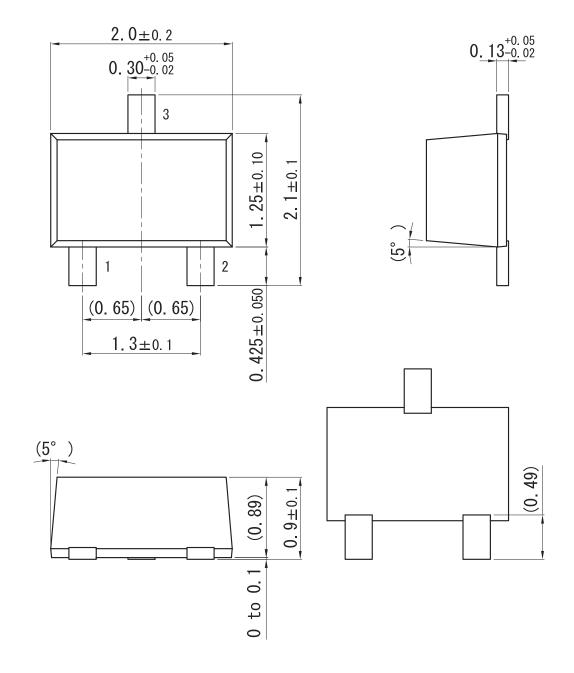
Collector current  $I_C$  (mA)

100

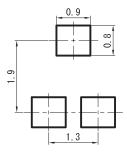


SMini3-F2-B





Land Pattern (Reference) (Unit: mm)



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